



30V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	Ι _D T _A = +25°C
2017	29mΩ @ V _{GS} = 10V	5.6A
30V	35mΩ @ V _{GS} = 4.5V	4.8A

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC Motor Control
- DC-AC Inverters

Features and Benefits

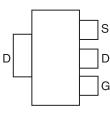
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

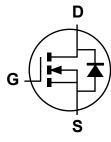
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See diagram below
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (approximate)



Top View



Pin Out - Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Qualification	Case	Packaging
DMN3032LE-13	Standard	SOT223	2,500 / Tape & Reel

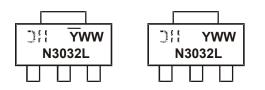
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V _{DSS}	30	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 5))/ = 10)/	T _A = +25°C T _A = +70°C	ID	5.6 4.1	А
Continuous Drain Current (Note 5) V _{GS} = 10V	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	ID	15.4 12.1	A
Maximum Continuous Body Diode Forward Current (Note 5)		Is	1.5	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)		I _{DM}	25	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	TA = +25°C	PD	1.8	W
Total Power Dissipation (Note 5)	TA = +70°C		1.1	
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ ext{ heta}JA}$	69	°C/W
Total Power Dissipation (Note 5)		PD	14	W
Thermal Resistance, Junction to Case (Note 5)		$R_{ ext{ heta}JC}$	8.7	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

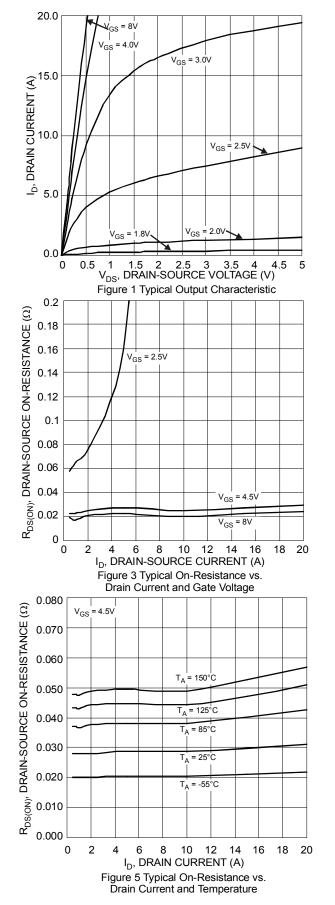
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current	I _{DSS}	_	—	1	μA	V _{DS} = 30V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	—	±100	nA	V_{GS} = ±20V, V_{DS} = 0V	
ON CHARACTERISTICS (Note 6)			_	_			
Gate Threshold Voltage	V _{GS(th)}	1	—	2	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D	_	22	29	mΩ	V _{GS} = 10V, I _D = 3.2A	
Static Drain-Source On-Resistance	R _{DS (ON)}	_	27	35		V _{GS} = 4.5V, I _D = 2.8A	
Forward Transfer Admittance	Y _{fs}	_	7	—	S	V _{DS} = 5V, I _D = 5.8A	
Diode Forward Voltage	V _{SD}	_	0.7	1.5	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 7)						·	
Input Capacitance	C _{iss}	_	498	—		V _{DS} = 15V, V _{GS} = 0V f = 1MHz	
Output Capacitance	C _{oss}	_	52	—	pF		
Reverse Transfer Capacitance	C _{rss}	_	45	—			
Gate Resistnace	Rg	_	2.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	11.3	_			
Gate-Source Charge	Q _{gs}	_	1.4	—	nC	V_{DS} = 15V, V_{GS} = 10V, I_D = 5.8A	
Gate-Drain Charge	Q _{gd}	_	2.1	—			
Turn-On Delay Time	t _{D(on)}	_	2.3	—		V _{DS} = 15V, V _{GS} = 10V,	
Turn-On Rise Time	tr	_	3.9	—	1		
Turn-Off Delay Time	t _{D(off)}	_	10	—	ns	$R_L = 2.6\Omega, R_G = 3\Omega$	
Turn-Off Fall Time	tr		1.9	_			

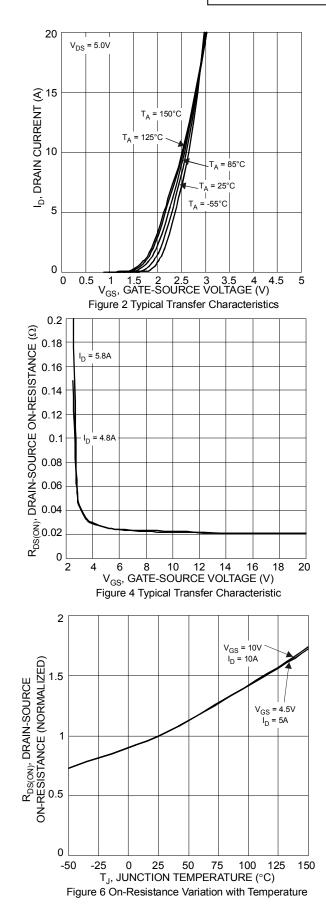
5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate 6 .Short duration pulse test used to minimize self-heating effect. Notes:

7. Guaranteed by design. Not subject to production testing.

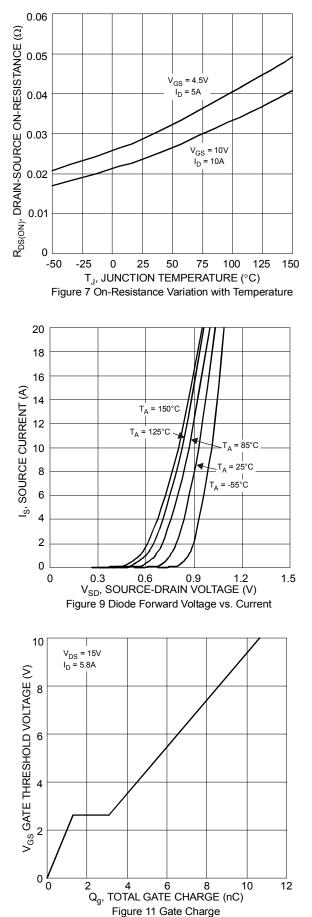


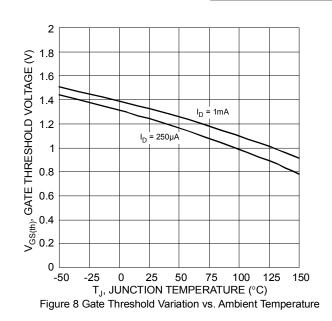
DMN3032LE

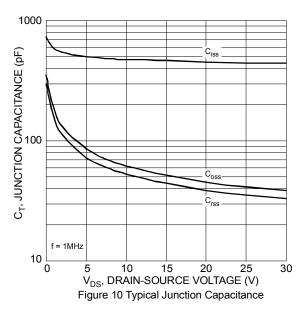




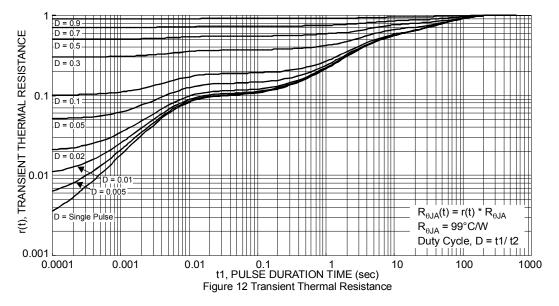






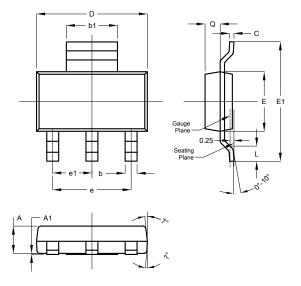






Package Outline Dimensions

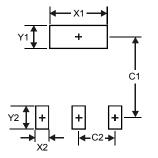
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
ш	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
X1	3.3			
X2	1.2			
Y1	1.6			
Y2	1.6			
C1	6.4			
C2	2.3			



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